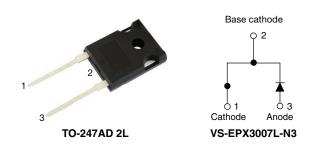
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Hyperfast Rectifier, 30 A FRED Pt[®]



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS									
I _{F(AV)}	30 A								
V _R	650 V								
V _F at I _F	1.6 V								
t _{rr} typ.	27 ns								
T _J max.	175 °C								
Package	TO-247AD 2L								
Circuit configuration	Single								

FEATURES

- Low forward voltage drop
- Hyperfast soft recovery time
- 175 °C operating junction temperature
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: TO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS						
Repetitive peak reverse voltage	V _{RRM}		650	V						
Average rectified forward current	I _{F(AV)}	T _C = 111 °C	30	Α						
Non-repetitive peak surge current	I _{FSM}	$T_C = 25 \text{ °C}, t_p = 8.3 \text{ ms}, \text{ half sine wave}$	170	A						
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C						

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	650	-	-				
Forward voltage	V _F	I _F = 30 A	-	2.1	2.5	V			
		I _F = 30 A, T _J = 150 °C	-	1.6	1.7				
		$V_{R} = V_{R}$ rated	-	0.02	30				
Reverse leakage current	I _R	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	300	μΑ			
Junction capacitance	CT	V _R = 650 V	-	22	-	pF			
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH			

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)									
PARAMETER	SYMBOL	TEST CON	DITIONS	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}$	Vµs, V _R = 30 V	-	35	-			
Reverse recovery time	t _{rr}	T _J = 25 °C		-	27	-	ns		
		T _J = 125 °C		-	88	-			
Doold recovery ourrept	I _{RRM}	T _J = 25 °C	$I_{\rm F} = 30 {\rm A}$	-	15	-	А		
Peak recovery current		T _J = 125 °C	dl _F /dt = 1000 A/µs V _B = 400 V	-	24	-	A		
	0	T _J = 25 °C		-	330	-			
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1350	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C				
Thermal resistance, junction to case	R _{thJC}		-	0.7	1.1	°C/W				
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.5	-					
Weight			-	5.5	-	g				
Weight			-	0.2	-	oz.				
Mounting torque			1.2 (10)	-	2.4 (20)	kgf · cm (lbf · in)				
Marking device		Case style TO-247 2L		EPX3	8007L					

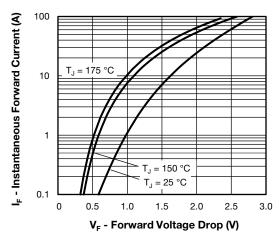


Fig. 1 - Typical Forward Voltage Drop Characteristics

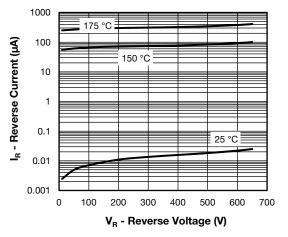


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

VS-EPX3007L-N3

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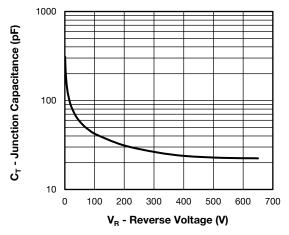


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

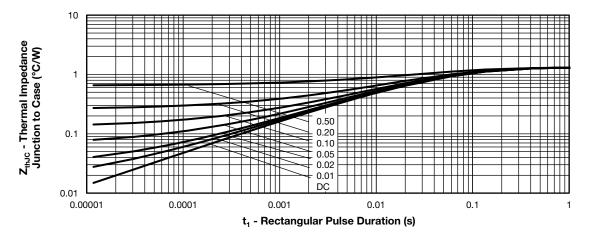
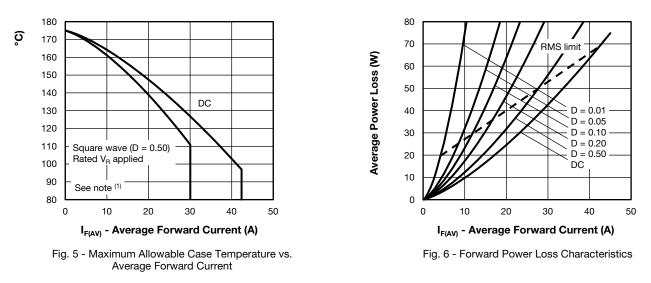


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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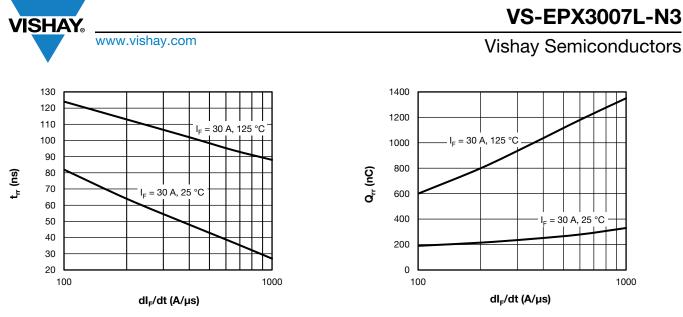


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

Fig. 8 - Typical Stored Charge vs. dl_F/dt

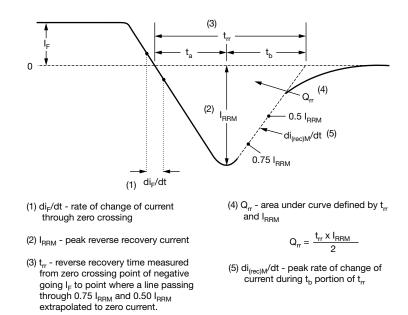


Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code	vs-	Е	Р	x	30	07	L	-N3
		_	-	~				
		2	3	4	5	6	7	8
	1 -	- Visl	nay Sem	niconduc	ctors pro	oduct		
	2 -	E =	single c	liode				
	3 -	- P=	TO-247	,				
	4 -	- X =	hyperfa	st recov	ery time	Э		
	5 -	Cur	rent coc	le (30 =	30 A)			
	6 -	Volt	age coo	de (07 =	650 V)			
	7 -	- L=	long lea	d				
	8 -			ntal digit en-free,		complia	nt and t	totally le
		110	nalog	,011 1100,	1.0110	complic	and and	io cany io

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-EPX3007L-N3	25	500	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95536							
Part marking information	www.vishay.com/doc?95648						



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TO-247AD 2L

DIMENSIONS in millimeters and inches



Section C - C, D - D

(b, b2)

(4)

View	<u>/ B</u>

SYMBOL	DL MILLIMETERS INCHES NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES				
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	STMDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209		E	15.29	15.87	0.602	0.625	3
A1	2.21	2.59	0.087	0.102		E1	13.46	-	0.53	-	
A2	1.50	2.49	0.059	0.098		е	5.46	BSC	0.215	5 BSC	
b	0.99	1.40	0.039	0.055		ØК	0.2	254	0.0	010	
b1	0.99	1.35	0.039	0.053		L	19.81	20.32	0.780	0.800	
b2	1.65	2.39	0.065	0.094		L1	3.71	4.29	0.146	0.169	
b3	1.65	2.34	0.065	0.092		ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035		Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033		Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3	R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4	S	5.51	BSC	0.217	' BSC	
D2	0.51	1.35	0.020	0.053			•		•		•

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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